

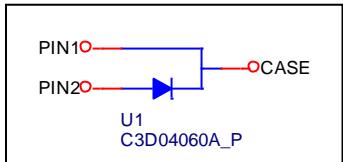
# Device Modeling Report

COMPONENTS: Silicon Carbide Schottky Diode  
PART NUMBER: C3D04060A  
MANUFACTURER: CREE  
REMARK: Professional Model



**Bee Technologies Inc.**

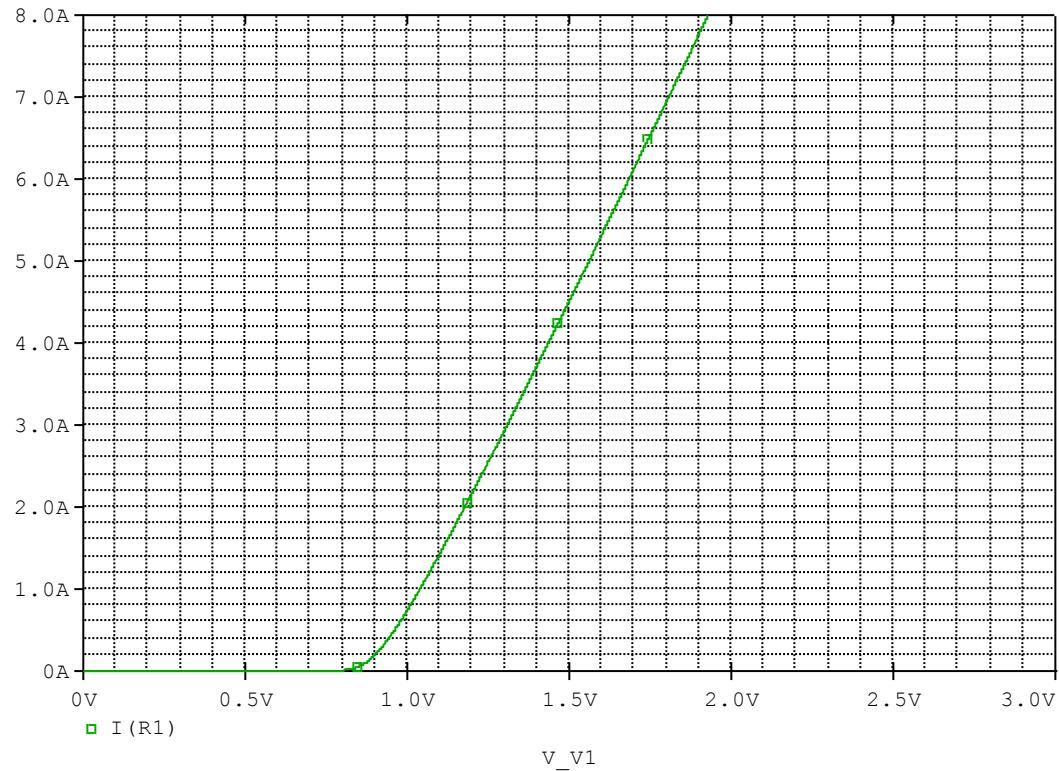
## Circuit Configuration



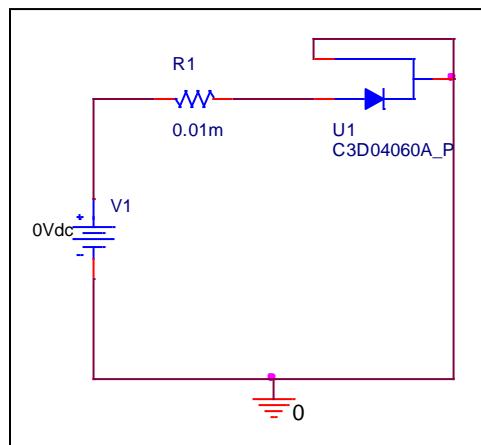
| PSpice model parameter | Model description                           |
|------------------------|---|
| IS                     | Saturation Current                          |
| N                      | Emission Coefficient                        |
| RS                     | Series Resistance                           |
| IKF                    | High-injection Knee Current                 |
| CJO                    | Zero-bias Junction Capacitance              |
| M                      | Junction Grading Coefficient                |
| VJ                     | Junction Potential                          |
| ISR                    | Recombination Current Saturation Value      |
| BV                     | Reverse Breakdown Voltage(a positive value) |
| IBV                    | Reverse Breakdown Current(a positive value) |
| TT                     | Transit Time                                |
| EG                     | Energy-band Gap                             |

## Forward Current Characteristic

### Circuit Simulation Result

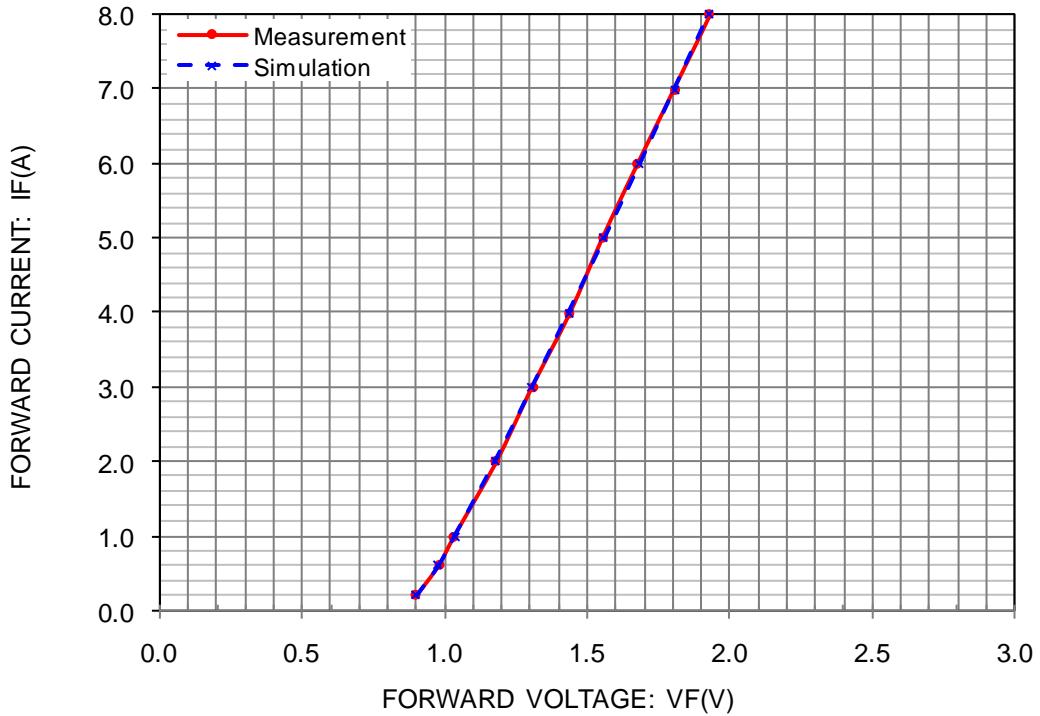


### Evaluation Circuit



## Comparison Graph

Circuit Simulation Result

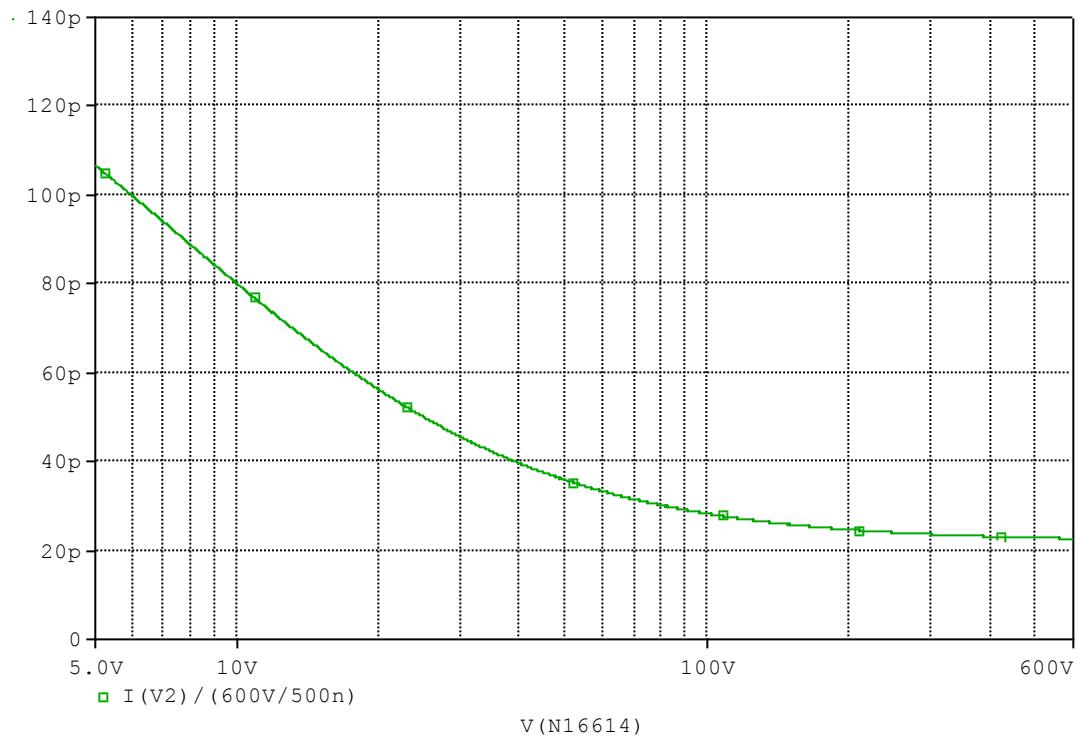


Simulation Result

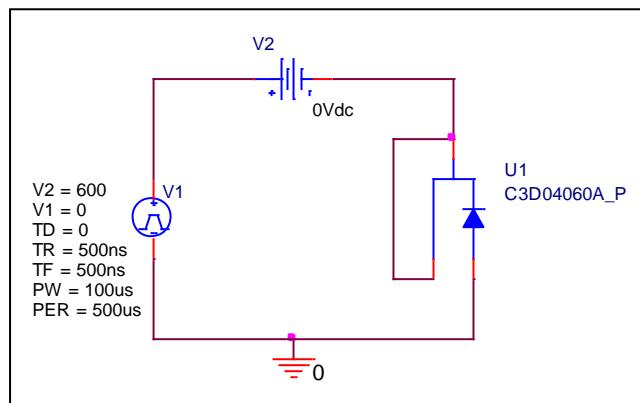
| $I_F$ (A) | $V_F$ (V)   |            | Error (%) |
|-----------|-------------|------------|-----------|
|           | Measurement | Simulation |           |
| 0.2       | 0.9000      | 0.9009     | 0.10      |
| 0.6       | 0.9800      | 0.9776     | -0.24     |
| 1.0       | 1.0350      | 1.0391     | 0.40      |
| 2.0       | 1.1800      | 1.1776     | -0.20     |
| 3.0       | 1.3100      | 1.3083     | -0.13     |
| 4.0       | 1.4400      | 1.4356     | -0.31     |
| 5.0       | 1.5550      | 1.5607     | 0.37      |
| 6.0       | 1.6800      | 1.6844     | 0.26      |
| 7.0       | 1.8100      | 1.8071     | -0.16     |
| 8.0       | 1.9300      | 1.9289     | -0.06     |

## Junction Capacitance Characteristic

### Circuit Simulation Result

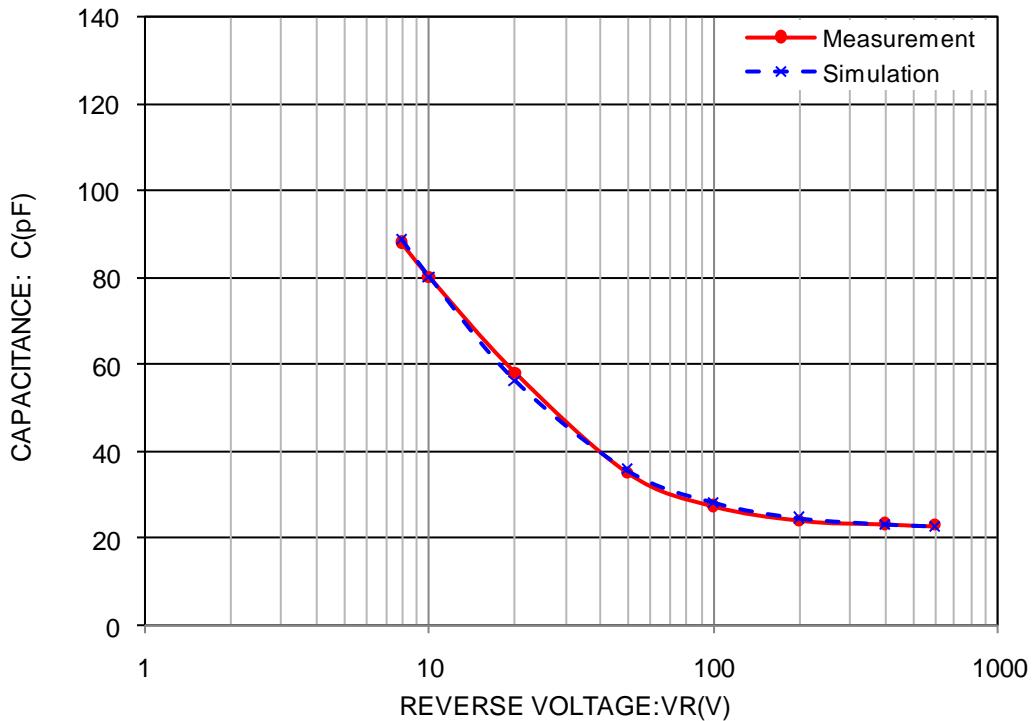


### Evaluation Circuit



## Comparison Graph

Circuit Simulation Result

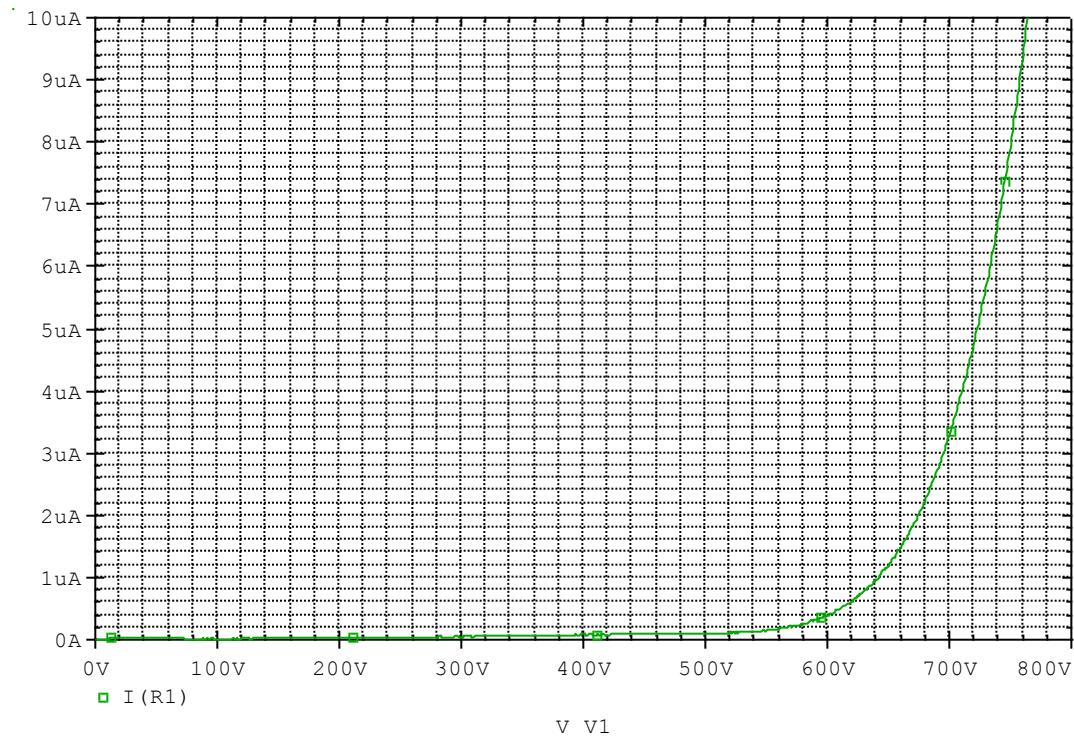


Simulation Result

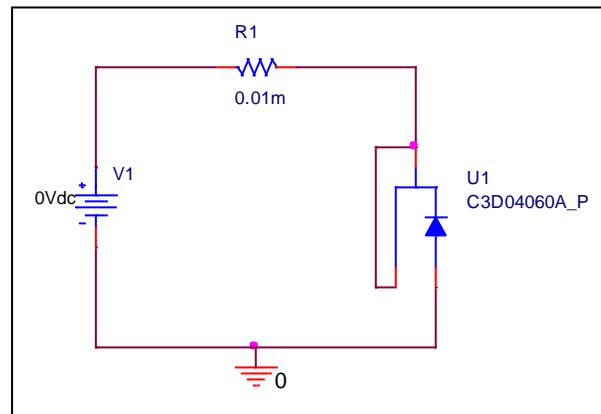
| VR(V) | C (pF)      |            | Error (%) |
|-------|-------------|------------|-----------|
|       | Measurement | Simulation |           |
| 8     | 88.000      | 88.671     | 0.76      |
| 10    | 80.000      | 80.070     | 0.09      |
| 20    | 58.000      | 56.219     | -3.07     |
| 50    | 35.000      | 35.838     | 2.39      |
| 100   | 27.500      | 28.273     | 2.81      |
| 200   | 24.000      | 24.696     | 2.90      |
| 400   | 23.300      | 23.125     | -0.75     |
| 600   | 23.000      | 22.672     | -1.43     |

## Reverse Characteristic

Circuit Simulation Result

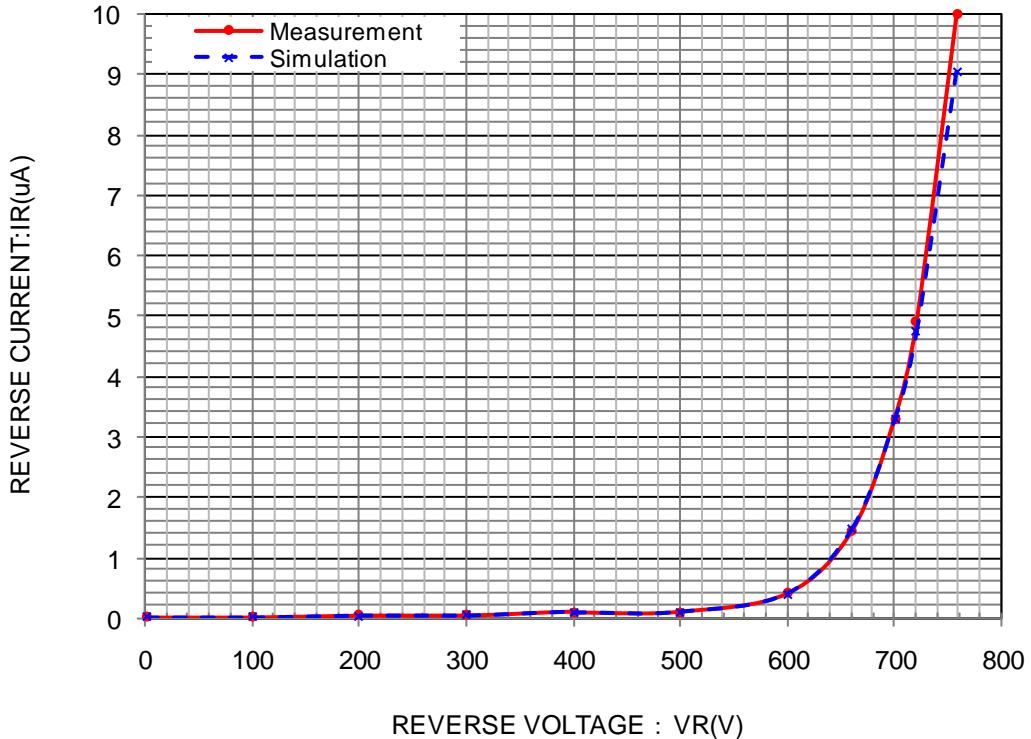


Evaluation Circuit



## Comparison Graph

### Circuit Simulation Result



### Simulation Result

| $V_R$ (V) | $I_R$ (uA)  |            | Error (%) |
|-----------|-------------|------------|-----------|
|           | Measurement | Simulation |           |
| 1         | 0.0110      | 0.0107     | -2.70     |
| 100       | 0.0140      | 0.0142     | 1.51      |
| 200       | 0.0350      | 0.0341     | -2.55     |
| 300       | 0.0450      | 0.0455     | 1.06      |
| 400       | 0.0850      | 0.0853     | 0.31      |
| 500       | 0.1000      | 0.0966     | -3.37     |
| 600       | 0.4000      | 0.3979     | -0.52     |
| 700       | 3.3000      | 3.2856     | -0.44     |